

DATA SHEET

74LVC573

Octal D-type transparent latch (3-State)

Product specification
Supersedes data of February 1996
IC24 Data Handbook

1997 Mar 12

Octal D-type transparent latch (3-State)

74LVC573

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- In accordance with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- Flow-through pin-out architecture
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74LVC573 is a high performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families. Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC573 is an octal D-type transparent latch featuring separate D-type inputs for each latch and 3-State outputs for bus oriented applications. A latch enable (LE) input and an output enable (\overline{OE}) input are common to all internal latches.

The '573' consists of eight D-type transparent latches with 3-State true outputs. When LE is HIGH, data at the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change each time its corresponding D-input changes.

When LE is LOW the latches store the information that was present at the D-inputs a set-up time preceding the HIGH-to-LOW transition of LE. When \overline{OE} is LOW, the contents of the eight latches are available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the latches.

The '573' is functionally identical to the '373', but the '373' has a different pin arrangement.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^\circ\text{C}$; $t_r = t_f \leq 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay D_n to Q_n LE to Q_n	$C_L = 50\text{pF}$ $V_{CC} = 3.3\text{V}$	4.3 4.6	ns
C_i	Input capacitance		5.0	pF
C_{PD}	Power dissipation capacitance per latch	Notes 1, 2	23	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacity in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
2. The condition is $V_i = \text{GND to } V_{CC}$.

ORDERING AND PACKAGE INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic SO	-40°C to $+85^\circ\text{C}$	74LVC573 D	74LVC573 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to $+85^\circ\text{C}$	74LVC573 DB	74LVC573 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to $+85^\circ\text{C}$	74LVC573 PW	74LVC573PW DH	SOT360-1

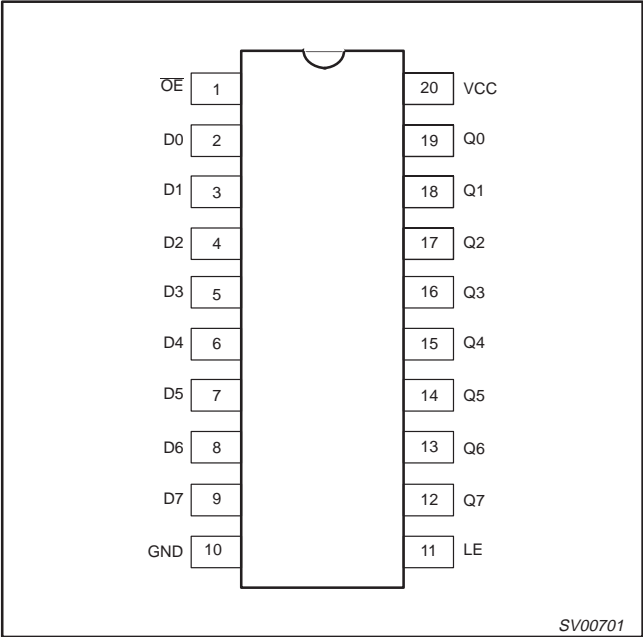
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	\overline{OE}	Output enabled input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	D_0 – D_7	Data inputs
19, 18, 17, 16, 15, 14, 13, 12	Q_0 – Q_7	3-State latch outputs
10	GND	Ground (0V)
11	LE	Latch enable input (active HIGH)
20	V_{CC}	Positive supply voltage

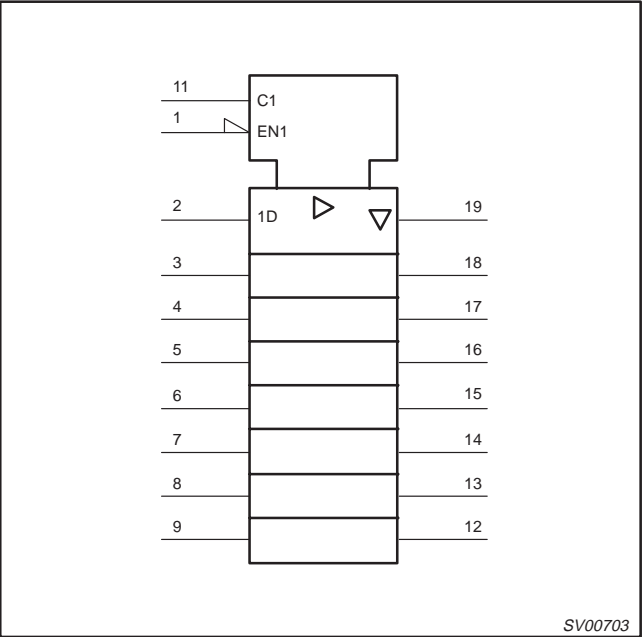
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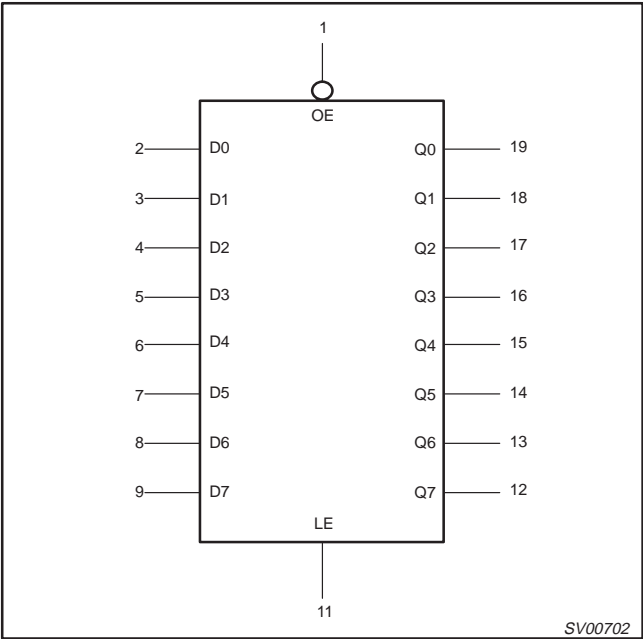
PIN CONFIGURATION



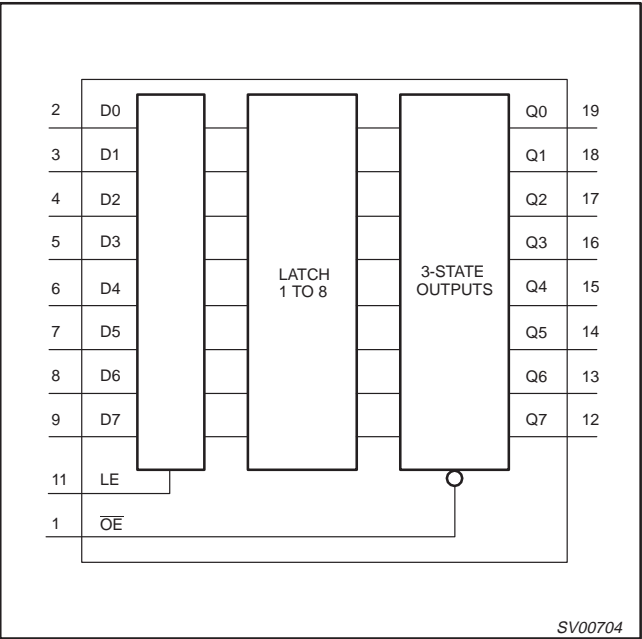
LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



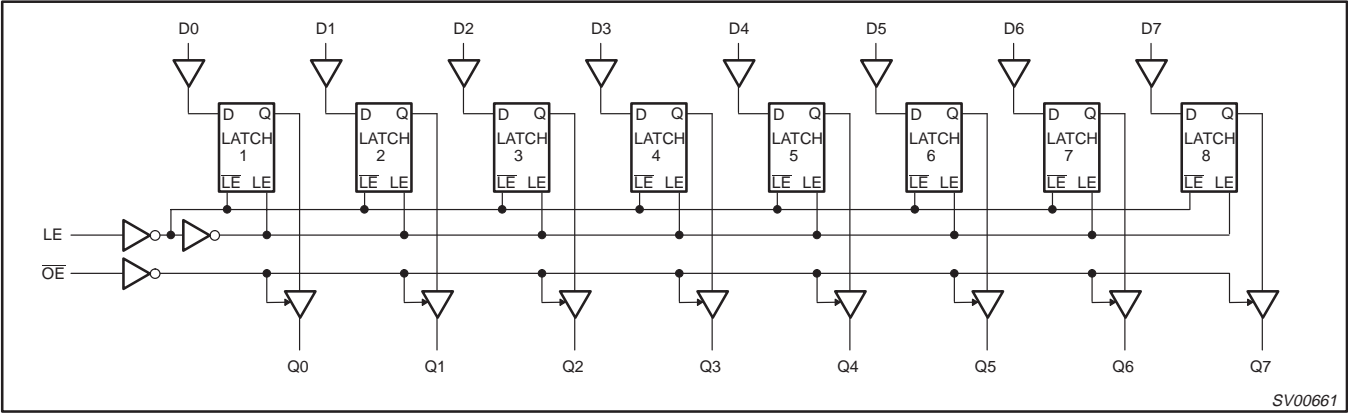
FUNCTIONAL DIAGRAM



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LOGIC DIAGRAM



FUNCTION TABLE

OPERATING MODES	INPUTS			INTERNAL LATCHES	OUTPUTS
	\overline{OE}	LE	Dn		Q0 to Q7
Enable and read register (transparent mode)	L	H	L	L	L
	L	H	H	H	H
Latch and read register	L	L	l	L	L
	L	L	h	H	H
Latch register and disable outputs	H	L	l	L	Z
	H	L	h	H	Z

H = HIGH voltage level
h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition
L = LOW voltage level
l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition
X = Don't care
Z = High impedance OFF-state

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V_{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V_{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
V_I	DC input voltage range		0	5.5	V
$V_{I/O}$	DC input voltage range for I/Os		0	V_{CC}	V
V_O	DC output voltage range		0	V_{CC}	V
T_{amb}	Operating free-air temperature range		-40	+85	°C
t_r, t_f	Input rise and fall times	$V_{CC} = 1.2$ to $2.7V$ $V_{CC} = 2.7$ to $3.6V$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +6.5	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	Note 2	-0.5 to +5.5	V
$V_{I/O}$	DC input voltage range for I/Os		-0.5 to $V_{CC} + 0.5$	V
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V_{OUT}	DC output voltage	Note 2	-0.5 to $V_{CC} + 0.5$	V
I_{OUT}	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		±100	mA
T_{stg}	Storage temperature range		-60 to +150	°C
P_{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2V	V _{CC}			V	
		V _{CC} = 2.7 to 3.6V	2.0				
V _{IL}	LOW level Input voltage	V _{CC} = 1.2V			GND	V	
		V _{CC} = 2.7 to 3.6V			0.8		
V _{OH}	HIGH level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5			V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}			
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6				
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 1.0				
V _{OL}	LOW level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA			0.40	V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA		GND	0.20		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA			0.55		
I _I	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND	Not for I/O pins		± 0.1	± 5	μA
I _{IHZ} /I _{ILZ}	Input current for common I/O pins	V _{CC} = 3.6V; V _I = V _{CC} or GND			± 0.1	± 15	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 3.6V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND			0.1	± 10	μA
I _{CC}	Quiescent supply current	V _{CC} = 3.6V; V _I = V _{CC} or GND; I _O = 0			0.1	20	μA
ΔI _{CC}	Additional quiescent supply current per input pin	V _{CC} = 2.7V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0			5	500	μA

NOTES:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0 V; t_r = t_f ≤ 2.5 ns; C_L = 50 pF

SYMBOL	PARAMETER	WAVEFORM	LIMITS						UNIT
			V _{CC} = 3.3V ± 0.3V			V _{CC} = 2.7V		V _{CC} = 1.2V	
			MIN	TYP ¹	MAX	MIN	MAX	TYP	
t _{PHL} /t _{PLH}	Propagation delay Dn to Qn	Figures 1, 5	1.5	4.3	7.8	1.5	8.0	21	ns
t _{PHL} /t _{PLH}	Propagation delay LE to Qn	Figures 2, 5	1.5	4.6	8.5	1.5	10	23	ns
t _{PZH} /t _{PZL}	3-State output enable time OE to Qn	Figures 3, 5	1.5	3.8	7.5	1.5	8.0	17	ns
t _{PHZ} /t _{PLZ}	3-State output disable time OE to Qn	Figures 3, 5	1.5	3.5	6.0	1.5	6.5	8.0	ns
t _W	LE pulse width HIGH	Figure 2	—	3.0	—	—	—	—	ns
t _{su}	Set-up time Dn to LE	Figure 4	1.0	0.2	—	1.0	—	—	ns
t _h	Hold time Dn to LE	Figure 4	1.0	0	—	1.0	—	—	ns

NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC WAVEFORMS

$V_M = 1.5V$ at $V_{CC} \geq 2.7V$
 $V_M = 0.5V * V_{CC}$ at $V_{CC} < 2.7V$
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_X = V_{OL}$ at $0.3V \geq 2.7V$
 $V_X = V_{OL} + 0.1V_{CC}$ at $V_{CC} < 2.7V$
 $V_Y = V_{OH} - 0.3V$ at $V_{CC} \geq 2.7V$
 $V_Y = V_{OH} - 0.1V_{CC}$ at $V_{CC} < 2.7V$

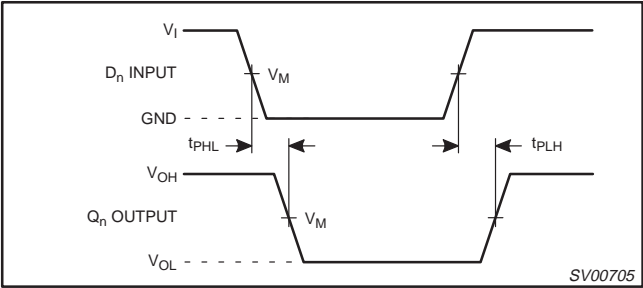


Figure 1. Input (Dn) to output (Qn) propagation delays.

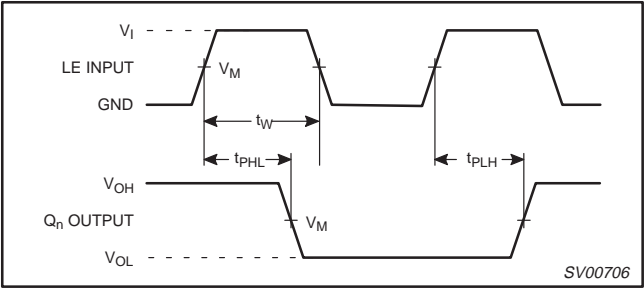


Figure 2. Latch enable input (LE) pulse width, the latch enable input to output (Qn) propagation delays.

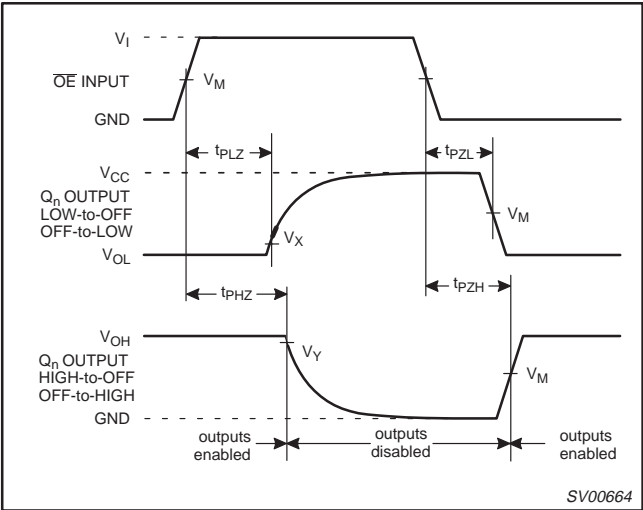


Figure 3. 3-State enable and disable times

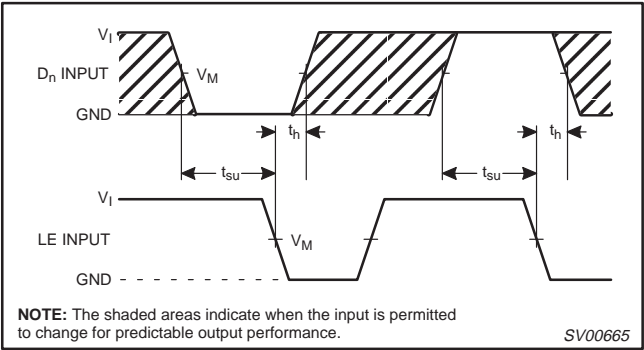


Figure 4. Data set-up and hold times for the Dn input to the LE input

TEST CIRCUIT

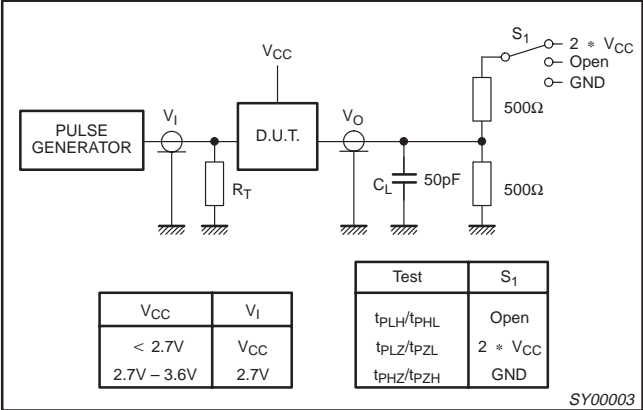


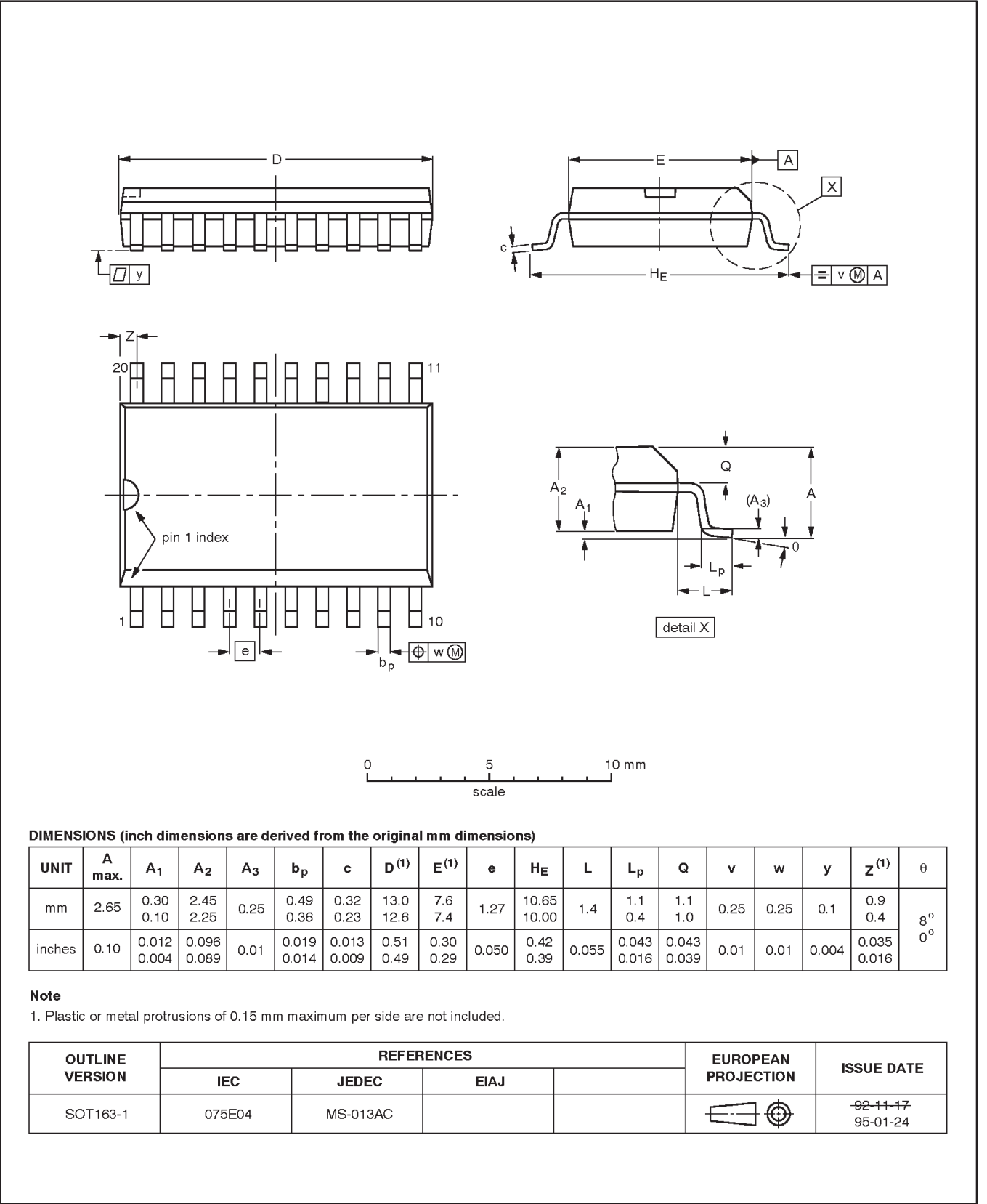
Figure 5. Load circuitry for switching times

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

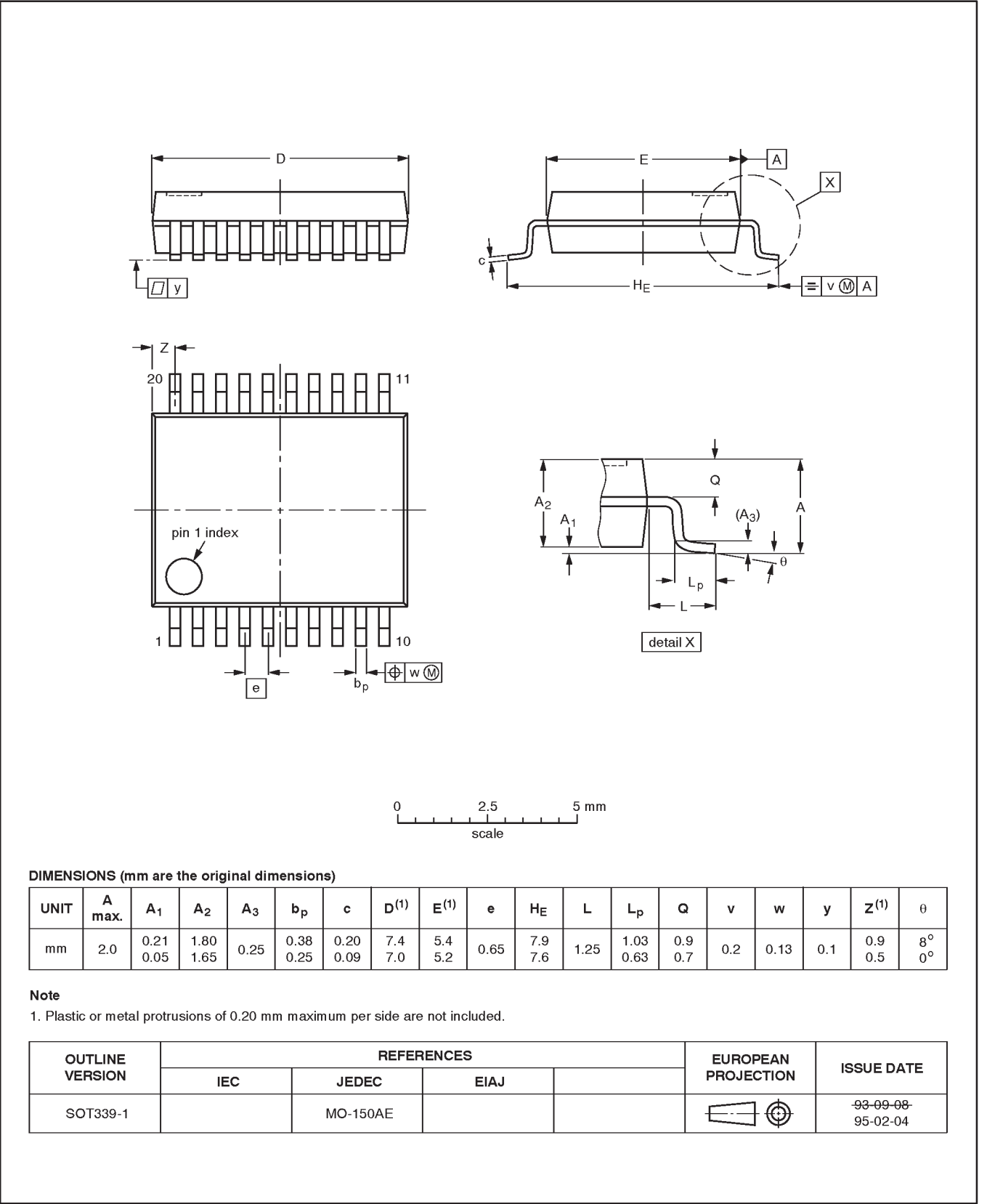


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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

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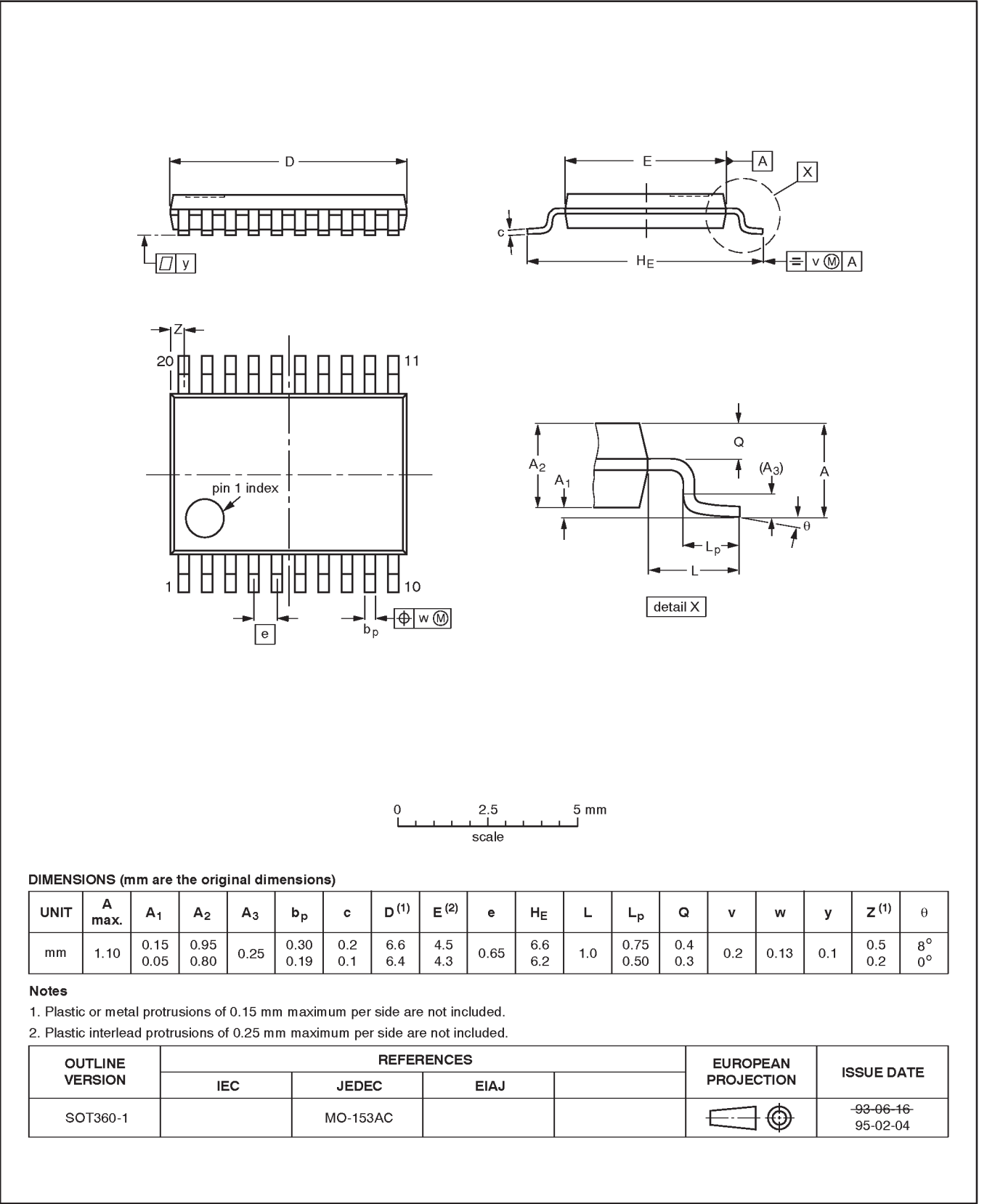


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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



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NOTES

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DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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811 East Arques Avenue
P.O. Box 3409
Sunnyvale, California 94088–3409
Telephone 800-234-7381

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